Electronic Devices

Mid Term Lecture - 04

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Reference book:

Electronic Devices and Circuit Theory (Chapter-2)

Robert L. Boylestad and L. Nashelsky, (11th Edition)



Objectives

- Diodes application : AND/OR gates
- Understand the process of rectification to establish a dc level from a sinusoidal ac input.

Logic OR gates

EXAMPLE 2.14 Determine V_o for the network of Fig. 2.39.

(1) $E = 10 \text{ V} \circ 1$ D_1 $O \text{ V} \circ 2$ D_2

Inputs of Diode, D1 and D2 are 1 (10 V) and 0 (0 V), respectively (Fig 2.39)

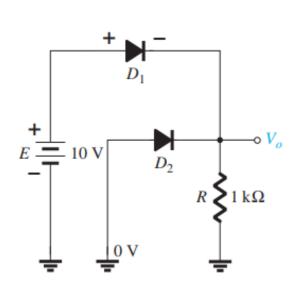


FIG. 2.40
Redrawn network of Fig. 2.39.

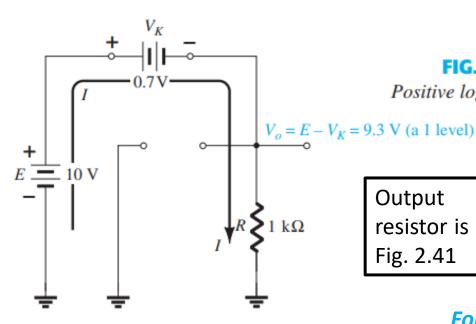


FIG. 2.41
Assumed diode states for Fig. 2.40.

FIG. 2.39

Positive logic OR gate.

Output across the resistor is 9.3 V (1 level) Fig. 2.41

For AND gates see the Example 2.15

 $1 k\Omega$

SINUSOIDAL INPUTS; HALF-WAVE

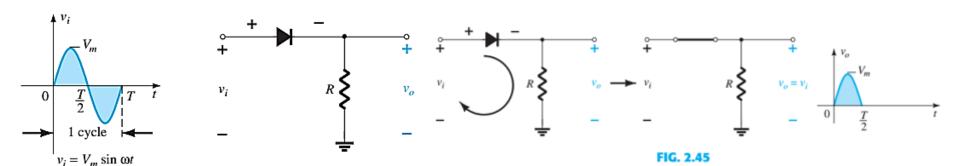


FIG. 2.44

Half-wave rectifier.

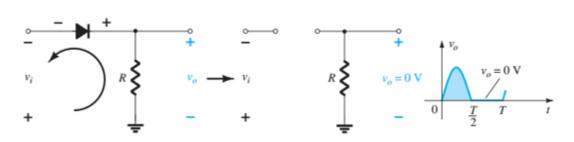
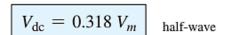
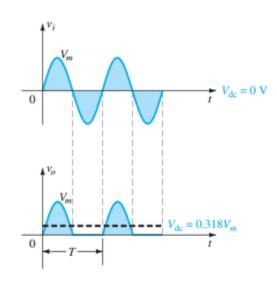


FIG. 2.46 Nonconduction region $(T/2 \rightarrow T)$.



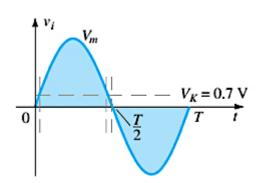


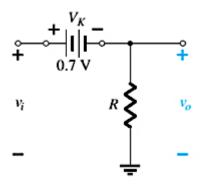
Conduction region $(0 \rightarrow T/2)$.

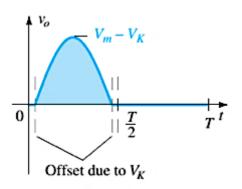
FIG. 2.47
Half-wave rectified signal.

HALF-WAVE RECTIFICATION

- The process of removing one-half the input signal to establish a dc level is called *halfwave rectification*.
- The effect of using a silicon diode with $V_K = 0.7 \text{ V}$ is demonstrated in below Figure for the forward-bias region. The applied signal must now be at least 0.7 V before the diode can turn "on."





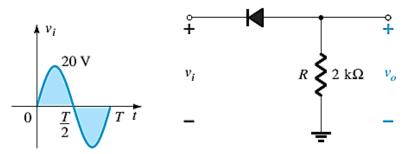


$$V_{\rm dc} \cong 0.318 (V_m - V_K)$$

HALF-WAVE RECTIFICATION

EXAMPLE 2.16

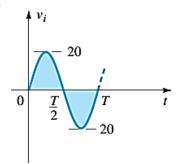
- a. Sketch the output v_o and determine the dc level of the output for the network of Fig. 2.49.
- b. Repeat part (a) if the ideal diode is replaced by a silicon diode.
- c. Repeat parts (a) and (b) if V_m is increased to 200 V, and compare solutions using Eqs. (2.7) and (2.8).

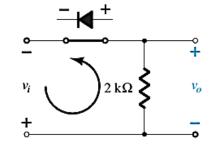


$$V_{\rm dc} = -0.318V_m = -0.318(20 \text{ V}) = -6.36 \text{ V}$$

FIG. 2.49

Network for Example 2.16.





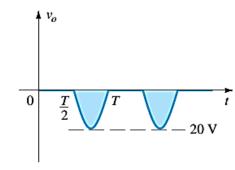


FIG. 2.50

Resulting v_o for the circuit of Example 2.16.

HALF-WAVE RECTIFICATION

b. For a silicon diode, the output has the appearance of Fig. 2.51, and $V_{\rm dc} \cong -0.318(V_m-0.7~{\rm V}) = -0.318(19.3~{\rm V}) \cong -6.14~{\rm V}$ The resulting drop in dc level is 0.22 V, or about 3.5%.

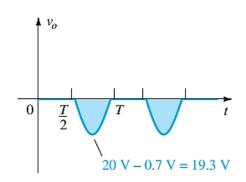


FIG. 2.51

Effect of V_K on output of Fig. 2.50.

c. Eq. (2.7):
$$V_{dc} = -0.318 V_m = -0.318(200 \text{ V}) = -63.6 \text{ V}$$

Eq. (2.8): $V_{dc} = -0.318(V_m - V_K) = -0.318(200 \text{ V} - 0.7 \text{ V})$
 $= -(0.318)(199.3 \text{ V}) = -63.38 \text{ V}$

PIV (PRV)

- It is the voltage rating that must not be exceeded in the reverse-bias region or the diode will enter the Zener avalanche region.
- Applying Kirchhoff's voltage law, it is fairly obvious that the PIV rating of the diode must equal or exceed the peak value of the applied voltage.

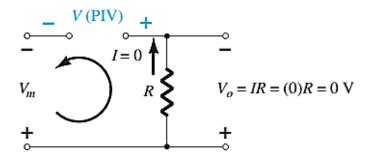


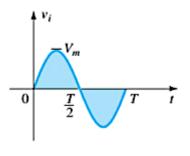
FIG. 2.52

Determining the required PIV rating for the half-wave rectifier.

PIV rating $\geq V_m$

half-wave rectifier

FULL-WAVE RECTIFICATION: BRIDGE NETWORK



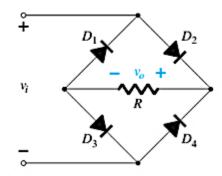
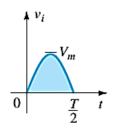


FIG. 2.53
Full-wave bridge rectifier.



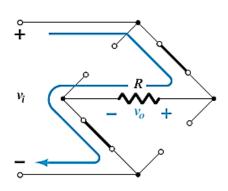


FIG. 2.55 Conduction path for the positive region of v_i .

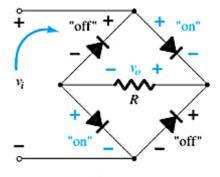
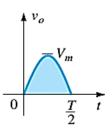
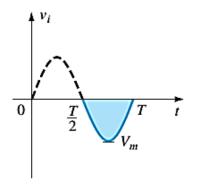


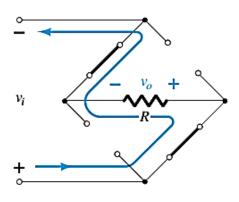
FIG. 2.54

Network of Fig. 2.53 for the period $0 \rightarrow T/2$ of the input voltage v_i .



BRIDGE NETWORK





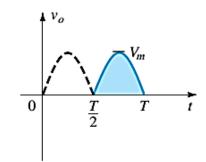
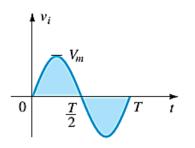


FIG. 2.56

Conduction path for the negative region of vi.



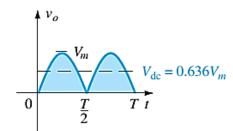
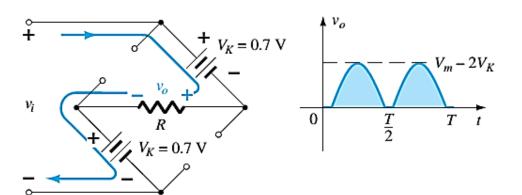


FIG. 2.57

Input and output waveforms for a full-wave rectifier.

BRIDGE NETWORK



$$V_{\rm dc} \cong 0.636(V_m - 2V_K)$$

FIG. 2.58

Determining $V_{o_{max}}$ for silicon diodes in the bridge configuration.

 $PIV \ge V_m$

full-wave bridge rectifier

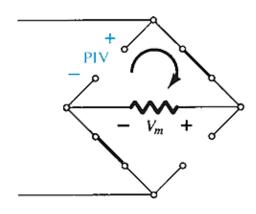


FIG. 2.59

Determining the required PIV for the bridge configuration.

CENTER-TAPPED TRANSFORMER

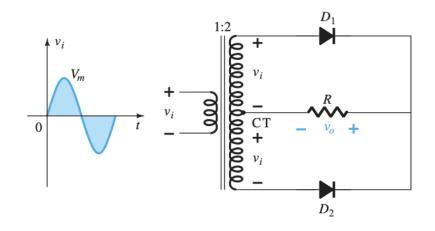
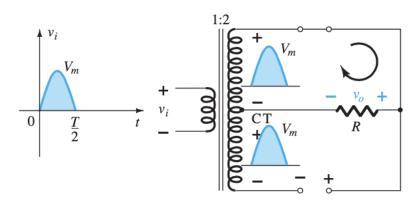
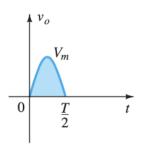


FIG. 2.60
Center-tapped transformer full-wave rectifier.

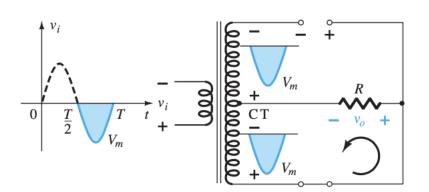
Network conditions for the positive region of v.

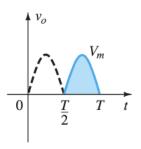




CENTER-TAPPED TRANSFORMER

Network conditions for the negative region of v.





$$PIV = V_{\text{secondary}} + V_R$$
$$= V_m + V_m$$

 $PIV \ge 2V_m$

CT transformer, full-wave rectifier

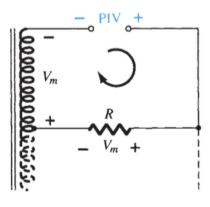


FIG. 2.63

Determining the PIV level for the diodes of the CT transformer full-wave rectifier.

EXAMPLE 2.17 Determine the output waveform for the network of Fig. 2.64 and calculate the output dc level and the required PIV of each diode.

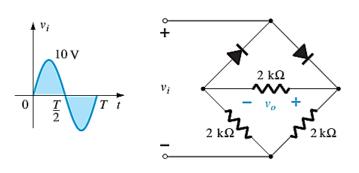
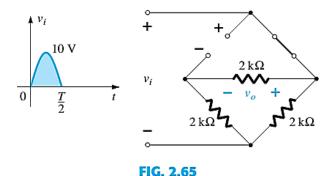


FIG. 2.64
Bridge network for Example 2.17.



Network of Fig. 2.64 for the positive region of v_i.

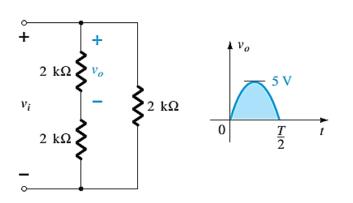


FIG. 2.66 Redrawn network of Fig. 2.65.

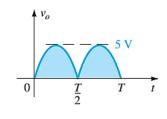


FIG. 2.67
Resulting output for Example 2.17.

$$V_{o_{\text{max}}} = \frac{1}{2}V_{i_{\text{max}}} = \frac{1}{2}(10 \text{ V}) = 5 \text{ V}$$

$$V_{\rm dc} = 0.636(5 \text{ V}) = 3.18 \text{ V}$$

PIV analysis

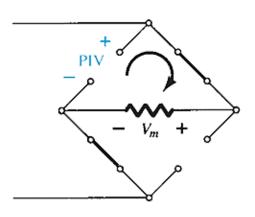


FIG. 2.59

Determining the required PIV for the bridge configuration.

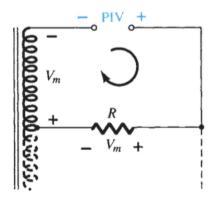


FIG. 2.63

Determining the PIV level for the diodes of the CT transformer full-wave rectifier.

$$PIV \ge V_m$$

full-wave bridge rectifier

$$PIV = V_{\text{secondary}} + V_R$$
$$= V_m + V_m$$

 $PIV \ge 2V_m$

CT transformer, full-wave rectifier

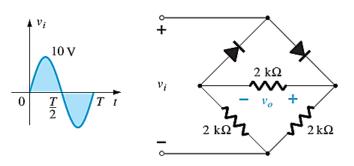


FIG. 2.64
Bridge network for Example 2.17.

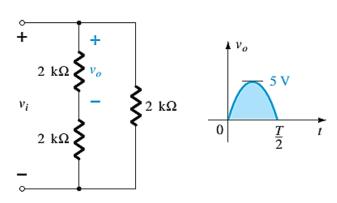


FIG. 2.66
Redrawn network of Fig. 2.65.

***The PIV as determined from Fig. 2.59 is equal to the maximum voltage across R, which is 5 V, or half of that required for a half-wave rectifier with the same input.

Thank You